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# Scalable Binder-Free Supersonic Cold Spraying of Nanotextured Cupric Oxide (CuO) Films as Efficient Photocathodes

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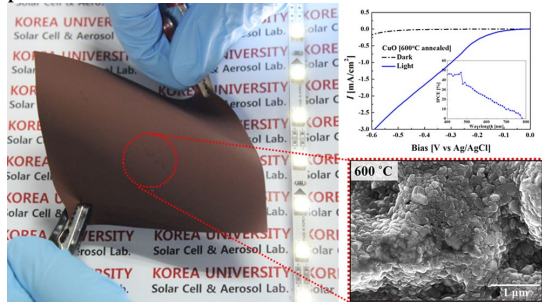
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## Abstract

We demonstrate production of nanotextured ptype cupric oxide (CuO) films via a low-cost scalable supersonic cold spray method in open air conditions. Simply sweeping the spray nozzle across a substrate produced a largescale CuO film. When used as hydrogen evolution photocathodes, these films produced photocurrent densities (PCD) of up to 3.1 mA/cm<sup>2</sup> under AM1.5 illumination, without the use of a cocatalyst or any additional heterojunction layers. Cu<sub>2</sub>O particles were supersonically sprayed onto an indium tin oxide (ITO) coated soda lime glass (SLG) substrate, without any solvent or binder. Annealing in air converted the Cu<sub>2</sub>O films to CuO, with a corresponding decrease in the bandgap and increase in the fraction of the solar spectrum absorbed. Annealing at 600 °C maximized the PCD. Increasing the supersonic gas velocity from ~450 to ~700 m/s produced denser films with greater surface roughness, in turn producing higher PCD. The nanoscale texture of the films, which resembles the skin of a dinosaur, enhanced their performance, leading to one of the highest PCD values in the literature. We characterized the films by X-ray diffraction, Raman spectroscopy, X-ray photoelectron spectroscopy, atomic force microscopy, scanning electron microscopy, and transmission electron microscopy to elucidate the origins of their outstanding performance. This supersonic cold spraying deposition has the potential to be used on a commercial scale for low cost mass production.



**Keywords:** supersonic cold spray, cupric oxide (CuO), cuprous oxide (Cu<sub>2</sub>O), water splitting, nanotextured surface

## 1 INTRODUCTION

Copper oxide has been used in numerous applications including solar water splitting,<sup>1-24</sup> photovoltaics,<sup>23,25-33</sup> gas sensing,<sup>34</sup> heterogeneous catalysis,<sup>7,16,35-37</sup> and lithium ion batteries.<sup>38-40</sup> Copper oxide is nontoxic, abundant, inexpensive, and, unlike other metal oxides used in photoelectrochemical (PEC) water splitting (i.e., TiO<sub>2</sub>, ZnO, Fe<sub>2</sub>O<sub>3</sub>, and WO<sub>3</sub>), it is an efficient light absorber in the visible region of the spectrum. Copper oxide is also a relatively good electrical conductor, which facilitates extraction of photogenerated charge carriers.<sup>7</sup> However, the limited stability of Cu<sub>2</sub>O under PEC water splitting conditions is still an issue. Cu<sub>2</sub>O can be reduced to

metallic copper by photogenerated electrons, i.e.,  $\text{Cu}_2\text{O} + \text{H}_2\text{O} + 2\text{e}^- \rightarrow 2\text{Cu} + 2\text{OH}^-$ .<sup>15</sup> Cupric oxide (CuO) has a bandgap in the range of 0.7–1.6 eV,<sup>41</sup> while  $\text{Cu}_2\text{O}$  has a bandgap in the range of 2.0–2.2 eV.<sup>19</sup> Compared to  $\text{TiO}_2$  or  $\text{Fe}_2\text{O}_3$  ( $E_g = 3.0$  and  $2.3$  eV, respectively), both CuO and  $\text{Cu}_2\text{O}$  have a lower bandgap, which enables them to absorb nearly half of the solar spectrum (including visible light), while  $\text{TiO}_2$  and  $\text{Fe}_2\text{O}_3$  can capture less than 10 and 25% of the solar spectrum (mostly ultraviolet light), respectively.<sup>10</sup> From this perspective, CuO is superior to  $\text{Cu}_2\text{O}$  because of its lower bandgap, in spite of other issues, such as recombination and its small redox potential. Another advantage of CuO is its large absorbance coefficient, which provides equivalent light absorption by a thinner film, increasing potential flexibility of the film.<sup>9</sup> The large negative conduction band values of CuO and  $\text{Cu}_2\text{O}$  (i.e.,  $-0.2$  V and  $-0.7$  V, respectively) allow them to be used as efficient hydrogen-generating electrodes. CuO and  $\text{Cu}_2\text{O}$  have theoretical maximum photocurrent densities (PCD) of 35 and 14.7 mA/cm<sup>2</sup>, respectively, under 1.5 AM irradiation.<sup>15</sup> To date, the highest PCD achieved is that reported by the Gratzel group<sup>7</sup> with a value of 7 mA/cm<sup>2</sup> using electrodeposited  $\text{Cu}_2\text{O}$ . They also reported a breakthrough in improving the stability of a copper oxide film by introducing multiple protective layers using ZnO and  $\text{TiO}_2$  together with platinum cocatalysts. However, the coating process requires at least five layers each of ZnO and  $\text{TiO}_2$ , which increases the manufacturing cost, not to mention the cost of materials such as platinum or palladium.<sup>14</sup>  $\text{Cu}_2\text{O}$  has a moderately high bandgap of 2.0–2.2 eV, which is larger than the required minimum water oxidation potential of 1.23 eV; however, the  $\text{Cu}_2\text{O}$  bandgap remains in the visible light range. For these reasons, much research has been devoted to investigating  $\text{Cu}_2\text{O}$  as a photocathode, especially since the work of Paracchino et al.<sup>7</sup>

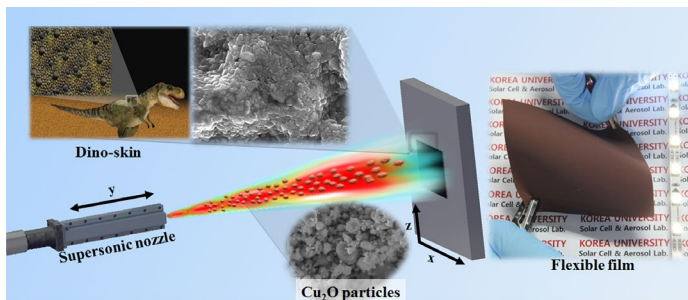


Figure 1. Schematic of cold spray deposition (middle inset image is the SEM image of CuO after air annealing).

Given the advantages of  $\text{Cu}_2\text{O}$ , there has been comparatively less research into CuO as a photocathode material. However, CuO is more stable than  $\text{Cu}_2\text{O}$ <sup>13,19</sup> and thus is often used as a protective layer over  $\text{Cu}_2\text{O}$ . Simple air annealing transforms  $\text{Cu}_2\text{O}$  into CuO. Furthermore, CuO has the advantage of a smaller bandgap, allowing it to absorb more of the solar spectrum, and producing its very high theoretical PCD of 35 mA/cm<sup>2</sup>. CuO films have been fabricated using sputtering,<sup>23,24</sup> spin coating,<sup>5,14,42</sup> direct anodization,<sup>22</sup> sol–gel spin-coating,<sup>15</sup> physical vapor deposition,<sup>19</sup> and hybrid microwave annealing<sup>17</sup> techniques. Most of these studies yielded PCD values below 2.0 mA/cm<sup>2</sup>. Notable exceptions are the work of Masudy-Panah et al. and Jang et al., who produced PCD values of 2.5 and 4.4 mA/cm<sup>2</sup>, respectively. Masudy-Panah et al.<sup>23</sup> showed that their enhanced PCD could be attributed to the increased effective surface area upon increasing the sputtering power used in CuO deposition. Jang et al.<sup>17</sup> also increased the surface area using hybrid microwave annealing process which produced a unique hierarchical leaf-shaped morphology. On the basis of this observation, we infer that increasing the surface area is a key factor in maximizing the PCD of the CuO film.

Here, we have increased the surface area of our CuO films by increasing the impact velocity of  $\text{Cu}_2\text{O}$  particles deposited by supersonic spray deposition. Supersonic spraying facilitates in situ nanotexturing of film surfaces via the high-speed impact. Nanotextured surfaces are obtained by the deposition of irregular nanoparticles that are pulverized upon impact. Subsequent annealing converts the films to CuO and improves film crystallinity. The supersonic cold spray deposition was conducted in open air conditions, and simply sweeping the nozzle across a substrate produced a large-scale CuO film. Therefore, this deposition method has the potential to be used on a commercial scale for low cost mass production. The films produced here were rigorously characterized by X-ray diffraction (XRD), Raman spectroscopy, X-ray photoelectron spectroscopy (XPS), atomic force microscopy (AFM), scanning electron microscopy (SEM), and transmission electron microscopy (TEM). The effect of the supersonic impact velocity on the PCD was also investigated. The mechanism of the improved PCD was explained by the change in bandgap and surface roughness as a function of the impact velocity. The nanotextured surface morphology interestingly resembles the skin of a dinosaur.

## 2 EXPERIMENTAL SECTION

**2.1. Supersonic Cold Spraying.** Figure 1 depicts the supersonic cold spraying method used here. Cu<sub>2</sub>O particles were sprayed at a supersonic velocity via a converging-diverging nozzle. Upon impact, they were pulverized, and their fragments adhered to a flexible substrate to produce a thin film. The Cu<sub>2</sub>O film was sufficiently conductive to turn on an LED light in a wired electrical circuit, as demonstrated in the right-hand inset of Figure 1. Films of 1–3 μm thickness were grown by sweeping the spray nozzle across the substrate 15 to 25 times at a scan speed of 10 mm/s. The pulverized fragments underwent in situ sintering upon impact, as their kinetic energy was converted to thermal energy. The supersonic gas velocity was determined by the operating pressure and temperature of the air, which were in the range of  $2 \leq P_0 \leq 4$  bar and  $250 \leq T_0 \leq 450$  °C, respectively (see Table 1), yielding an isentropic air velocity of 553–829 m/s. As the ball-milled particles used here are small, their Stokes number is also small ( $Stk \approx 10^{-4}$ ), and the velocity of the entrained nanoparticles nears that of the air.<sup>43,44</sup> More details on cold spraying deposition are provided in our previous work.<sup>45–47</sup>

Table 1. Operating Conditions for the Supersonic Cold Spraying System

Conditions	
Pressure [bar]	2–4
gas preheating temperature [°C]	250–450
traverse speed [mm/s]	10
nozzle-to-substrate distance [mm]	50

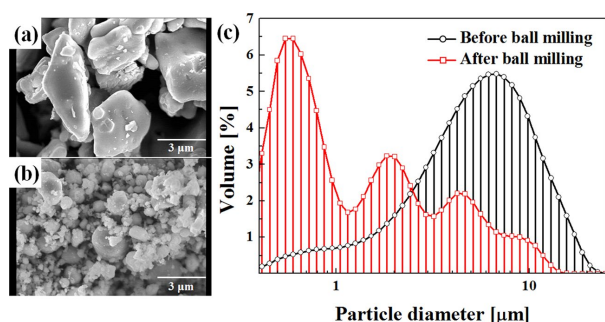


Figure 2. SEM images of Cu<sub>2</sub>O particles (a) before and (b) after 4 days of ball milling; and (c) particle size distribution of Cu<sub>2</sub>O particles from a laser-diffraction particle size analyzer before and after ball milling.

**2.2. Cuprous Oxide (Cu<sub>2</sub>O) Precursor.** As shown in Figure 2a and b, Cu<sub>2</sub>O particles with an average size of 6.5 μm were ball-milled into smaller particles, which were then fed into the cold spray coating system, as depicted in Figure 1. As shown in Figure 2c, the particle size was significantly reduced after 4 days of ball milling. The milled material had a broad trimodal size distribution. A substantial fraction of the particles was below 1 μm in diameter, which is desirable for the cold spraying process. If a particle is too large, then the particle response time is also large, and the particle is not accelerated to the gas velocity before impact. If the particle size is too small, then the particles do not attain sufficient momentum to be fragmented upon impact. On the basis of our prior experience, an average particle size of  $1 \pm 0.5$  μm is most effective.<sup>45</sup>

**2.3. Characterization of the Photoelectrodes.** The distribution of particle sizes was analyzed using a laser-diffraction particle size analyzer (LS 13 320, Beckman Coulter, U.S.A.), as well as by direct scanning electron microscopy (SEM, S-5000, Hitachi, JAPAN) imaging. Crystallinity and crystal phase were assessed using powder X-ray diffraction (XRD, SmartLab, Rigaku, JAPAN) across a range of  $10^\circ < 2\theta < 80^\circ$  and by Raman spectroscopy, using a confocal Raman spectrometer (NRS-3100) with a 532 nm laser excitation source. The chemical composition of the surface of the films was studied by X-ray photoelectron spectroscopy (XPS, Theta probe base system, Thermo Fisher Scientific Co.). The morphology of the CuO thin films was studied using SEM (S-5000, Hitachi, JAPAN) at 10 kV and transmission electron microscopy (TEM, JEM 2100F, JAPAN). The TEM specimen was prepared using focused ion beam milling (FIB, LYRA3 XMH, Tescan). Atomic force microscopy (AFM, XE-100, Park Systems, KOREA) was used to measure the surface roughness of the films.

**2.4. Photoelectrochemical (PEC) Measurements.** A single cell with three electrodes was used for PEC measurements. Each of the CuO films was used as the working electrode, while an Ag/AgCl rod and platinum wire were used as the pseudo reference and counter electrodes, respectively. These three electrodes were positioned with interelectrode distances of 10 mm, and their positions were fixed in order to acquire consistent data and minimize transport limitations in the electrolyte. The sample area exposed to the illuminating light was 0.25 cm<sup>2</sup>. A 1 M KOH (pH = 14) solution was used as the electrolyte. Nitrogen gas was purged through the electrolyte solution to remove any dissolved oxygen before the measurements. Artificial sunlight from a xenon arc lamp (Newport, Oriel Instruments, U.S.A.) equipped with an AM 1.5 filter was used as a light source with an intensity of 100 mW/cm<sup>2</sup>. All photocurrent data were recorded using a potentiostat (VersaSTAT-3, Princeton Applied Research, U.S.A.) with a scan rate of 10 mV/s and an applied voltage ranging from 0.5 to –0.6 V relative to Ag/AgCl.

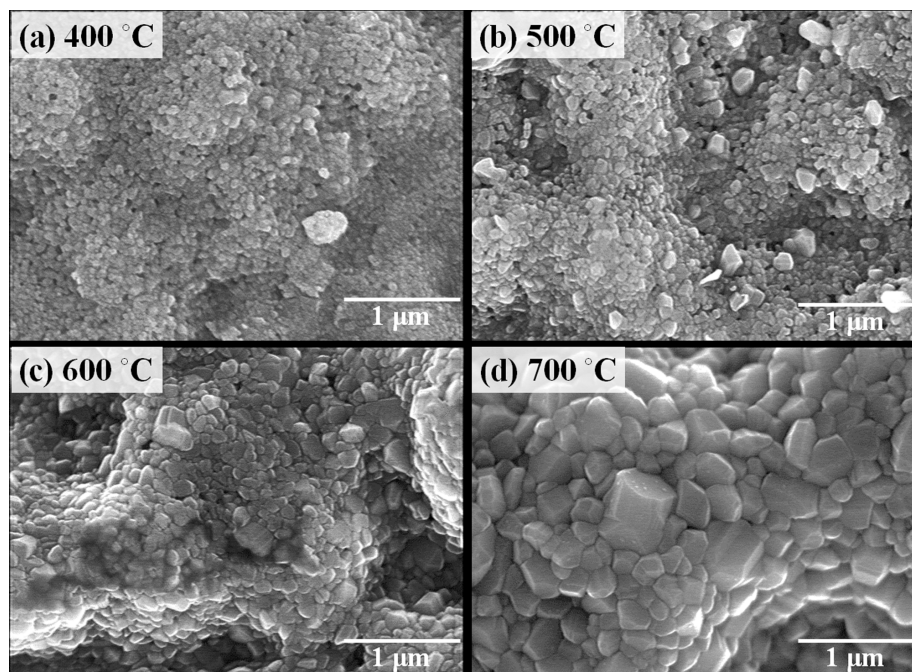


Figure 3. Effect of annealing temperature on the CuO surface morphology, (a) 400 °C, (b) 500 °C, (c) 600 °C, and (d) 700 °C.

**3.1. Effects of Annealing.** Figure 3 shows the surface morphology of films annealed at 400 °C, 500 °C, 600 °C, and 700 °C. All the films exhibited surface curvature (peaks and valleys at a length scale much larger than the individual particles). This irregular surface, which forms spontaneously upon fragmentation of the impacting particles, resembles the self-induced honeycomb structure previously reported for aerosol-deposited films.<sup>48</sup> This type of spontaneous nanostructuring enhances the accessible surface area of the film. Figure 3 also shows the increase in crystal size with increasing annealing temperature, consistent with sharpening of XRD peaks in Figure 4. The small pulverized nanoparticles are of uniform crystal size, as shown in Figure 3a and are substantially smaller than the precursor Cu<sub>2</sub>O particles. Upon increasing the annealing temperature, these small crystals coalesced and grew, as is evident from Figure 3b. At 600 °C, the growth of the crystals on the irregular surface of the film resembles the rough skin of a dinosaur. Crystal growth can improve the PEC performance of the CuO by improving the transport of charge carriers and reducing the total number of recombination centers. However, excessive growth may hinder water splitting performance by reducing the effective surface area, which is generally inversely proportional to the crystal size.

Figure 4 shows XRD patterns from the Cu<sub>2</sub>O nanoparticles, the as-deposited film, and films annealed in air at 400 °C, 500 °C, 600 °C, and 700 °C for 30 min; all films were fabricated under the operating conditions of  $P_0 = 4$  bar,  $T_0 = 450$  °C. Diffraction peaks at  $2\theta$  values of 29.6°, 36.4°, 42.4°, and 61.4° corresponds to the (110), (111), (200), and (220) planes of Cu<sub>2</sub>O, respectively. After annealing, the Cu<sub>2</sub>O diffraction peaks are replaced by those of CuO, with two prominent peaks at 35.66° and 38.85°, corresponding to lattice spacings (d spacings) of 0.25 and 0.23 nm, respectively. These peaks arise from diffraction by the  $(-111)/(002)$  and  $(111)/(200)$  planes of CuO (JCPDS card no. 801917). Annealing at temperatures above 400 °C did not result in any further phase change. In air, the conversion of Cu<sub>2</sub>O to CuO occurs below 400 °C.<sup>19,49</sup> Valladares et al.<sup>49</sup> and Basnet et al.<sup>19</sup> reported that the transformation of Cu<sub>2</sub>O into CuO started at 150–200 °C. Although the peak positions do not change with increasing annealing temperature above 400 °C, the peaks do become sharper at higher annealing temperatures, indicating improved crystallinity and increased crystallite size. The crystal size was determined from the Debye–Scherrer formula,  $D = 0.9\lambda/(\beta \cos \theta)$ , where  $D$  is the crystal size,  $\lambda$  is the X-ray wavelength,  $\beta$  is the full width at half-maximum (fwhm) of the diffraction peak, and  $\theta$  is the diffraction angle. The estimated crystal size increased from 32.1 nm to 34.7, 40.7, and 43.5 nm as the annealing temperature increased from 400 to 700 °C. It should be noted that the diffraction peak at  $2\theta = 31^\circ$  arises from the ITO coating on the substrate. At higher temperatures of 600 °C and 700 °C, the ITO peak is not visible because it is smaller relative to the CuO peaks, which become stronger with increasing annealing temperature.

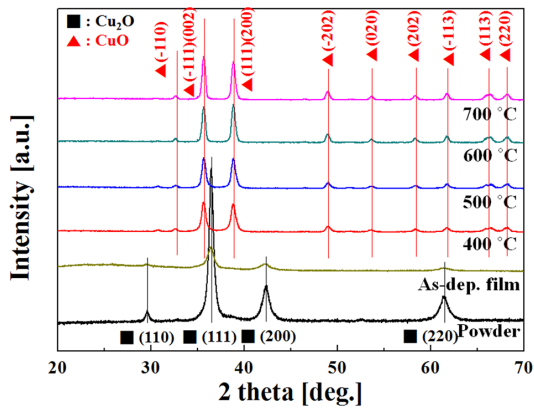


Figure 4. XRD pattern of Cu<sub>2</sub>O powder, as-deposited film, and films annealed at 400 °C, 500 °C, 600 °C, and 700 °C.

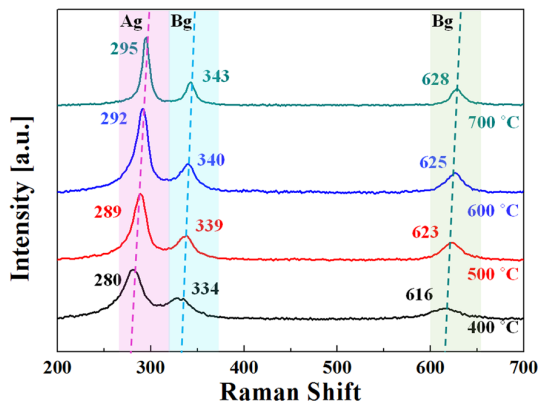


Figure 5. Raman spectra of CuO films annealed at 400 °C, 500 °C, 600 °C, and 700 °C.

We also employed Raman spectroscopy, with 532 nm excitation, scanning from 200–700 cm<sup>-1</sup> to characterize the CuO films annealed in air at 400 °C, 500 °C, 600 °C, and 700 °C. CuO is included in the C<sub>2h</sub> space group with binary molecules for a given unit primitive cell. CuO is also included in the normal modes of the center zone, namely,  $\Gamma_{RA} = 4Au + 5Bu + Ag + 2Bg$ , which comprises 3 acoustic modes of (Au + 2Bu), 6 infrared active modes of (3Au + 3Bu), and 3 Raman active modes of (Ag + 2Bg).<sup>50</sup> Raman spectra of the CuO films deposited on an indium tin oxide (ITO)-coated soda lime glass (SLG) substrate (Figure 5) show three peaks corresponding to the three Raman active optical phonons at 280, 334, and 616 cm<sup>-1</sup>. The peak at 280 cm<sup>-1</sup> is due to the Ag mode and the peaks at 334 and 616 cm<sup>-1</sup> are due to the Bg modes.<sup>51</sup> Raman peaks of the CuO film became sharper and stronger and shifted to higher wavenumbers with increasing annealing temperature. For example, the peak at 280 cm<sup>-1</sup> shifted to 289, 292, and 295 cm<sup>-1</sup>, while the fwhm of the peaks decreased from 19.93 cm<sup>-1</sup> to 15.66, 14.24, and 8.54 cm<sup>-1</sup> as the annealing temperature increased from 400 °C to 700 °C. The peak positions after 700 °C annealing are very close to those reported for bulk, singlecrystalline CuO, which are 297, 344, and 629 cm<sup>-1</sup>.<sup>52</sup>

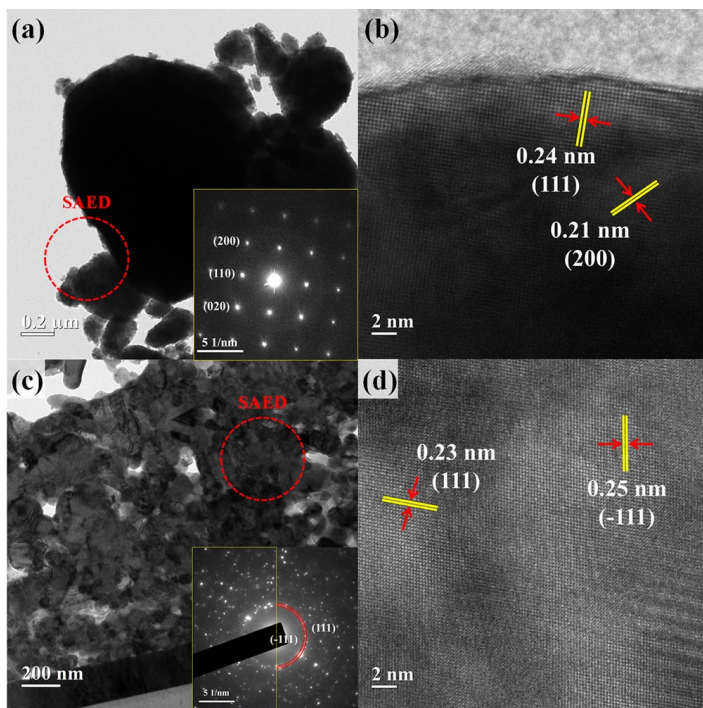


Figure 6. (a) Low magnification TEM image, Inset: Selected area electron diffraction (SAED) pattern, (b) High-resolution TEM image (HRTEM) of  $\text{Cu}_2\text{O}$  powder, (c) Low magnification TEM image Inset: SAED pattern, and (d) HRTEM image of  $\text{CuO}$  film.

The morphology and crystallographic structure of the  $\text{Cu}_2\text{O}$  particles and  $\text{CuO}$  film were also analyzed by TEM. Figure 6a and b displays TEM images of the  $\text{Cu}_2\text{O}$  particles. Figure 6a shows the low magnification TEM image and the selected-area electron diffraction (SAED) pattern (as an inset). The SAED pattern from the region marked by the red circle corresponds to the expected pattern for diffraction from  $\text{Cu}_2\text{O}$  along the [002] zone axis, with spots due to diffraction by the (200), (110), and (020) planes. The high-resolution TEM (HRTEM) image shown in Figure 6b shows clear lattice fringes at spacings of 0.24 and 0.21 nm, which were assigned to the (111) and (200) plane of monoclinic  $\text{Cu}_2\text{O}$ , respectively.<sup>53,54</sup> Figure 6c displays a low-magnification TEM image of the  $\text{CuO}$  film, which was prepared by a focused ion beam (FIB) technique. The SAED pattern (inset) shows two diffraction rings on the image corresponding to (111) and (-111) planes, respectively, along with numerous higher-order diffraction spots. The complexity of the pattern reflects the polycrystalline nature of the film. The detailed microstructure of the  $\text{CuO}$  film was revealed by HRTEM, as shown in Figure 6d. The lattice fringes between two planes of an isolated particle were calculated to be 0.23 and 0.25 nm, which were assigned to the (111) and (-111) planes of monoclinic  $\text{CuO}$ , respectively.<sup>42,55,56</sup> The HRTEM and SAED analyses confirmed the phase transformation into  $\text{CuO}$ .

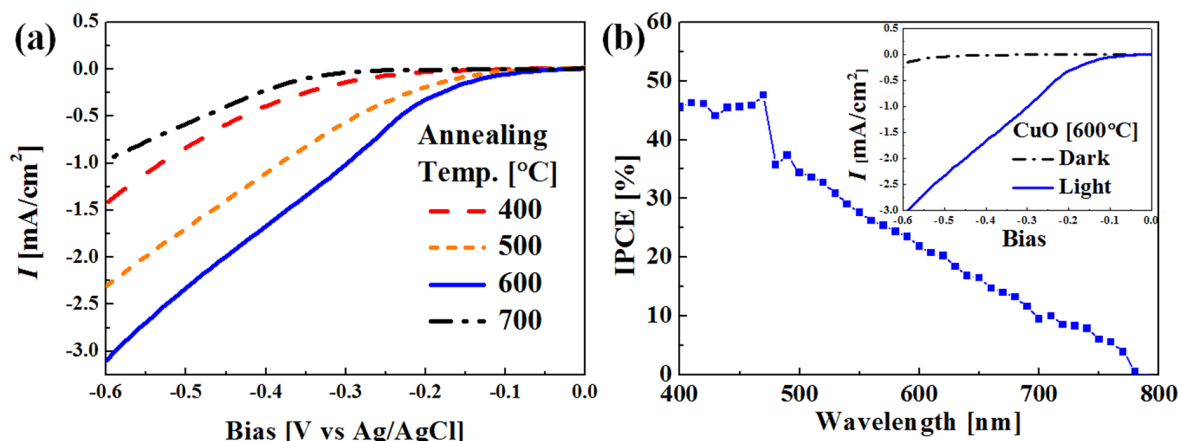


Figure 7. (a) Effect of annealing temperature on the current–potential curves of  $\text{CuO}$  photocathodes measured at 1 sun (1.5 AM filter) illumination in 1 M KOH (pH = 14). (b) IPCE of  $\text{CuO}$  photocathode. Inset: Dark and light current–potential curves for 600 °C.

The performance of the cold sprayed CuO films as photocathodes for PEC water-splitting was studied by measuring PCD vs voltage with respect to the Ag/AgCl reference electrode. The results for CuO films annealed at temperatures of 400 °C, 500 °C, 600 °C, and 700 °C are shown in Figure 7a. All of these films were deposited using a fixed air pressure and temperature of  $P_0 = 4$  bar and  $T_0 = 450$  °C. All measurements were performed under AM 1.5 (100 mW/cm<sup>2</sup>) illumination and using 1 M KOH (pH = 14) as the electrolyte. A platinum wire was the counter electrode and CuO was the working photocathode. Current–potential (I–V) curves were measured with (light) and without (dark) illumination. The dark current densities of the films were very low, typically a few  $\mu$ A, as shown in the inset in Figure 7b. The low dark current demonstrates that the PCD values under illumination are not due to simple corrosion or other nonphotoinitiated processes, although the small current near  $-0.6$  V may reflect the onset of corrosion reactions. Under illumination, photogenerated electron–hole pairs form in the valence band of the CuO film. After separation, the electrons travel to the conduction band of CuO and reduce water molecules at the solid–liquid interface, generating H<sub>2</sub>(g) and OH<sup>-</sup>(aq). The OH<sup>-</sup> is oxidized at the counterelectrode to produce O<sub>2</sub> and water. Paracchino et al.<sup>7</sup> used atomic layer deposition (ALD) to deposit TiO<sub>2</sub> and ZnO layers, which produced a PCD value of  $-7.6$  mA/cm<sup>2</sup> at 0.25 V while promoting the electron transport or mobility. In addition, these TiO<sub>2</sub> and ZnO layers protected the Cu<sub>2</sub>O (cuprous) layer from corrosion by avoiding the direct contact between Cu<sub>2</sub>O and electrolyte. Without the ALD layers, they achieved a PCD value of  $-2.4$  mA/cm<sup>2</sup>, which is less than our best case of  $-3.1$  mA/cm<sup>2</sup> shown in Figure 7a. As shown in Figure 7a, the onset potential for each film was in the range of  $-0.1$  V to  $-0.25$  V. From 400 °C to 500 °C to 600 °C, the onset potential moved to the right, producing higher PCD. At 600 °C, PEC performance reached a maximum of  $-3.1$  mA/cm<sup>2</sup> at  $-0.6$  V. Annealing at 700 °C dramatically diminished the PCD. The maximum PCD values, at  $-0.6$  V, obtained for films annealed at 400 °C, 500 °C, 600 °C, and 700 °C were  $-1.4$ ,  $-2.3$ ,  $-3.1$ , and  $-1.0$  mA/cm<sup>2</sup>, respectively. Note that  $-0.6$  V is the potential limit at which the film corrosion begins, yielding a nonzero dark current value. As mentioned earlier, there is a trade-off between crystal size and effective surface area. Smaller crystal size can provide a larger accessible surface area for reaction. However, if the crystal size is too small, then charge carrier transport will be inhibited. Improving crystallinity reduces the concentration of defect sites at which photogenerated charge carriers can recombine and improves carrier mobility and charge separation.<sup>57,58</sup> Thus, there is crystal size that optimizes the trade-off between improved charge carrier transport and reduced reactive surface area. The XRD pattern from Figure 4 shows the crystallinity of the 600 °C film is nearly equivalent to that of the 700 °C film. However, as shown in the SEM of Figure 3, the 600 °C film maintains a much smaller particle or crystallite size at the film surface, providing a much larger accessible surface area and number of sites for PEC. In addition, the onset potential is also significantly influenced by the postannealing temperature. The onset potential for the film postannealed at 600 °C is about  $-0.1$  V which shifted significantly to  $-0.25$  V after 700 °C annealing. Comparing the SEM images of films annealed at 600 and 700 °C reveals that the film annealed at 700 °C not only has larger average crystal size, and therefore smaller surface area, but is also significantly more faceted. Reconstruction of the film to expose only low energy facets may reduce its catalytic activity, i.e., the most reactive sites are likely to be at edges, vertices, and high-energy facets, many of which have been removed by annealing at 700 °C. In addition, higher annealing temperature increases the possibility of diffusion of impurities from the ITO-coated SLG into the CuO film, introducing defect sites that can serve as recombination centers for charge carriers. Hence, multiple factors may contribute to the decreased performance of the film annealed at 700 °C.

Figure 7b shows the incident photon-to-current efficiency (IPCE) data of the 600 °C film acquired at  $-0.6$  V vs Ag/AgCl for a wavelength range of 400–800 nm. IPCE is an indicator of light harvesting capability in the tested wavelength range. The onset of photocurrent near 800 nm corresponds to an effective band gap of about 1.5 eV, which is near the optimum bandgap for light harvesting. The CuO film showed a maximum IPCE of 47.6% at  $\lambda = 470$  nm, well into the visible portion of the solar spectrum. This IPCE value of 47.6% is quite high in comparison with previous studies: Hsu et al.<sup>59</sup> fabricated CuO nanowires on a copper foil via thermally transferring and reported an IPCE value of 15%. Wang et al.<sup>18</sup> used a wet chemical method and a hydrothermal process to fabricate ZnO/CuO bilayers and reported an IPCE value of 10%.



Table 2. Cold Spray Operation Details

	case 1	case 2	case 3	case 4	case 5	case 6	case 7	case 8	case 9
operating pressure (bar)	2	2	2	3	3	3	4	4	4
operating temperature (°C)	250	350	450	250	350	450	250	350	450
gas velocity (m/s)	553	585	615	677	716	753	746	789	829
Stokes no. $\times 10^{-4}$ (Stk)	3.79	4.13	4.43	4.64	5.05	5.43	5.11	5.56	5.98
sheet resistance ( $\Omega/\text{sq}$ )	41.2	43.4	44.5	51.6	44.9	51.5	53.7	57.5	72.7
roughness ( $\mu\text{m}$ )	0.10	0.15	0.17	0.10	0.14	0.17	0.10	0.15	0.18
photocurrent density ( $\text{mA}/\text{cm}^2$ )	-0.5	-0.7	-1.8	-0.7	-1.2	-2.3	-1.5	-1.9	-3.1
crystal size (nm)	37.9	37.5	37.9	37.0	38.8	39.7	37.9	38.8	40.7

<sup>a</sup>Note that velocity from Case 7 is lower than that from Case 6.

**3.2. Effect of Impact Velocity.** Successful cold spray deposition depends on achieving appropriate gas velocity, which determines the kinetic energy of the impacting particles. Here, we varied the air pressure and temperature of the gas supplied to the nozzle to change the particle impact velocity and studied the effects on the PEC performance. Particles entrained into the supersonic stream quickly reach the gas stream velocity. Their ability to respond to changes in gas velocity is characterized by a Stokes number (Stk), defined as  $\text{Stk} = \tau_p/\tau_g$ , where  $\tau_p = \rho_p D^2/(18 \mu_g)$  is the particle response time to the surrounding supersonic stream, and  $\tau_g = d/V_e$  is the characteristic time for impingement of the supersonic stream;  $\rho_p$  and  $D$  are the particle density and diameter, respectively;  $\mu_g$  is the gas dynamic viscosity, and  $d$  and  $V_e$  are the nozzle exit diameter and air velocity. Isentropic gas velocity at the supersonic nozzle exit is calculated as follows:

$$V_e = \sqrt{2c_p T_0 [1 - (P_e/P_0)^{(\gamma-1)/\gamma}]} \quad (1)$$

where  $c_p$  is the specific heat, and  $T_0$  and  $P_0$  are the carrier source temperature and pressure, respectively. The specific heat ratio of an air was  $\gamma = 1.4$ . The pressure at the nozzle exit is  $P_e$ . The gas velocity at the nozzle exit was multiplied by a factor of 0.8 to estimate the particle velocity of  $V_p$  (i.e.,  $V_p \approx 0.8V_g$ ), based on the calculated Stokes number.<sup>43</sup> Table 2 summarizes the nozzle exit velocity and Stokes number for various combina-

tions of pressure and temperature of the carrier gas. The electrical sheet resistance of the CuO film was in the range of 41–73  $\Omega/\text{sq}$ , which is relatively low compared to other oxide films such as reduced graphene oxide. This high electrical conductivity is important in supporting carrier transport across the film, which is necessary for achieving high PCD values.

There have been some reports that Cu<sub>2</sub>O and CuO composites yield the best PEC performance.<sup>13</sup> This may be because the light absorption and catalytic activity of the two copper oxides complement one another, such that the best PEC performance was achieved from optimal proportions of the two copper oxides, which were adjusted by controlling the annealing temperature.<sup>49</sup> However, in our case, the as-deposited Cu<sub>2</sub>O film was not capable of allowing sufficient current flow and thus no PCD was detected. This poor performance of the Cu<sub>2</sub>O film was probably because of the poor crystallinity of the as-deposited film, as shown in Figure 3. In our case, the films were intensely densified and a surface with severe curvature was produced by increasing the impact velocity. The film densification had a favorable effect on the electron–hole transfer. The severe curvature of the films increased the effective surface area for maximal interfacial PEC activity.

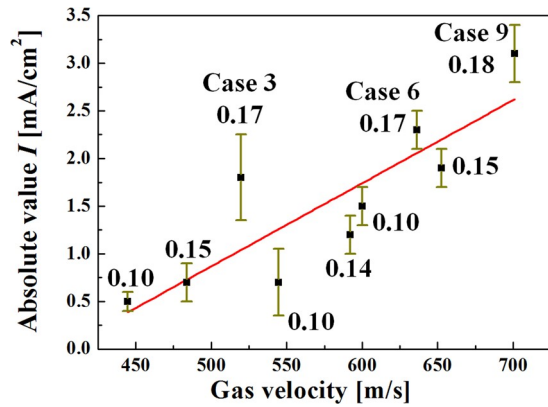


Figure 8. Effect of gas velocity (operating conditions) on the current– potential curves of CuO photocathodes measured at 1 sun (1.5 AM filter) illumination in 1 M KOH (pH = 14). The numbers shown for all points are the surface roughness values in microns.

Figure S1 shows SEM images of the CuO films annealed at 600 °C for the various impact velocities summarized in Table 2. Film densification is clearly shown as voids are removed with increasing impact velocity. There is no discernible difference in the surface morphology for the  $P_0 = 2$  bar cases (which are Cases 1, 2, and 3 in Table 2). However, Case 3 produced the best PCD ( $-1.8$  mA/cm<sup>2</sup>) of all three cases. For the  $P_0 = 3$  bar cases, the appearance of the “dinosaur skin” texture gradually progresses and is apparent in Case 6. While comparing the  $P_0 = 4$  bar cases, the surface texturing appears to be similar; however, the roughness was highest for Case 9. There is a common factor in Cases 3, 6, and 9: They are the cases with the highest roughness among the compared cases. Thus, we conclude that surface roughness is the major factor dominating the PEC performance for the cold sprayed films, which we have achieved by increasing the impact velocity.

Table 3. Comparison of the PEC Performance of the Present CuO Thin Films with Literature Values

coating method	incident light [mW/cm <sup>2</sup> ]	Reactant solution [M]	applied potential [V Ag/AgCl] <sup>f</sup>	pH	photocurrent density [mA/cm <sup>2</sup> ]	reference
sputtering	125	0.4 <sup>a</sup>	-0.50	11	-0.24	24
spin coating	100	1.0 <sup>b</sup>	-0.55	14	-1.20	35
spin coating	100	1.0 <sup>b</sup>	-0.55	14	-1.20	10
direct anodization	N.A.	0.5 <sup>c</sup>	-0.36	7.29	-0.36	22
spin-coating	100	0.1 <sup>d</sup>	-0.60	5.84	-0.55	15
spin coating	100	0.2 <sup>e</sup>	-0.55	9.2	-1.50	14
hybrid microwave annealing	100	1.0 <sup>d</sup>	-0.55	6	-4.40	17
physical vapor deposition	100	0.5 <sup>d</sup>	-0.50	6.4	-0.24	19
sputtering	100	0.1 <sup>d</sup>	-0.55	5.84	-2.50	23
cold spraying	100	1.0 <sup>b</sup>	-0.60	14	-3.10	present work

Figure 8 clearly shows the pattern of increasing PCD with increasing impact velocity. First, this improved photocathode performance with increasing impact velocity can be explained by the associated reduction in the bandgap (see Figure S2).

Second, the rougher surface morphology was another reason behind the higher PCD values (see the roughness data in microns for Cases 3, 6, and 9). Films with a roughness greater than  $R_z = 0.15$  μm tended to yield higher PCD values. Roughness alone cannot be the only reason behind this trend because sometimes a smaller roughness (as in Case 7 with a roughness of 0.1 μm) produces a higher PCD value as compared to cases with higher roughness (as in Cases 2 and 5 with a roughness of 0.15 and 0.14 μm, respectively). The film densification effect also contributes to the enhancement of the electron–hole transfer with increasing impact velocity. However, there is strong evidence to show that roughness has a strong influence on the overall PEC performance.

[Table 3](#) compares the PEC performance of our CuO films against films from previous studies reported since 2010. Our supersonic cold sprayed CuO films exhibited a PCD of  $-3.1 \text{ mA/cm}^2$ , which is the best of all the reported values except for the PCD reported by Jang et al.,<sup>17</sup> which was  $-4.4 \text{ mA/cm}^2$ . The high performance of our films is remarkable considering that they are produced by a rapid, scalable, and non vacuum process. To coat the  $7 \times 7 \text{ cm}^2$  sized film using supersonic cold spraying (see the inset in [Figure 1](#)) required a spraying time of less than 30 s using one nozzle, and the process could be carried out under open atmospheric conditions. Other methods such as sputtering or PVD require a vacuum chamber, and as a result are time-consuming and not readily scalable. Spin coating is simple, but much slower, and makes inefficient use of film precursors by ejecting most of the material from the spinning surface. In conclusion, none of the previously reported PCD values compared favorably with our current value of  $-3.1 \text{ mA/cm}^2$ . Jang et al. reported a higher PCD value of  $-4.4 \text{ mA/cm}^2$  using a hybrid microwave annealing process with a silicon susceptor, which required both post thermal treatments and microwave synthesis.<sup>17</sup> Jang et al. showed that the leaf-like structures of the CuO film they produced provided an increased surface area and thus a larger number of interfacial activities, which is in agreement with our findings herein. Compared to the hybrid microwave annealing process, our cold spraying method is simpler and scalable and thus would be beneficial to the commercialization of the technology. A  $7 \times 7 \text{ cm}^2$  CuO film deposited on a flexible copper foil was fabricated within 30 s of spraying, demonstrating the scalability and potential use in commercial applications.<sup>46,47,60</sup>

## CONCLUSIONS

Supersonic cold spraying was used to deposit Cu<sub>2</sub>O nano- particles on an ITO-coated SLG substrate for the fabrication of photocathodes for use in solar water splitting. The deposited Cu<sub>2</sub>O films were sintered at various annealing temperatures to convert them to CuO and improve their crystallinity. The optimal annealing temperature was 600 °C, which produced a moderate crystal size that optimized the trade-off between high surface area of small crystals and better charge carrier transport in larger crystals. The supersonic gas temperature and pressure were varied in the range of  $250 < T_0 < 450 \text{ °C}$  and  $2 < P_0 < 4 \text{ bar}$ , respectively. The CuO film fabricated at  $T_0 = 450 \text{ °C}$  and  $P_0 = 4 \text{ bar}$  yielded the best PCD of  $-3.1 \text{ mA/cm}^2$  and exhibited the highest roughness and densification due to the highest impact speed.

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